

Features

- High speed
 - 25 ns
- CMOS for optimum speed/power
- Low active power
 - 880 mW
- Low standby power
 - 220 mW
- Transistor-transistor logic (TTL)-compatible inputs and outputs
- Automatic power-down when deselected

Functional Description

The CY7C197N is a high-performance CMOS static RAM organized as 256 K words by 1 bit. Easy memory expansion is provided by an active LOW Chip Enable ($\overline{CE}$) and three-state drivers. The CY7C197N has an automatic power-down feature, reducing the power consumption by 75% when deselected.

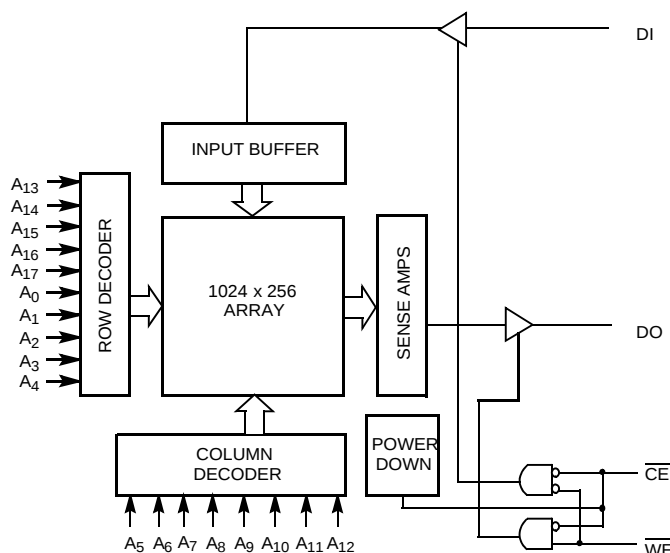
Writing to the device is accomplished when the Chip Enable ($\overline{CE}$) and Write Enable ($\overline{WE}$) inputs are both LOW. Data on the input pin (D_{IN}) is written into the memory location specified on the address pins (A_0 through A_{17}).

Reading the device is accomplished by taking chip enable ($\overline{CE}$) LOW while Write Enable ($\overline{WE}$) remains HIGH. Under these conditions the contents of the memory location specified on the address pins will appear on the data output (D_{OUT}) pin.

The output pin stays in a high-impedance state when Chip Enable ($\overline{CE}$) is HIGH or Write Enable ($\overline{WE}$) is LOW.

The CY7C197N uses a die coat to insure alpha immunity.

Logic Block Diagram

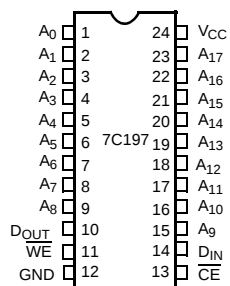


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Pin Configurations

Figure 1. 24-pin DIP (Top View)



Selection Guide

Description	-25
Maximum access time (ns)	25
Maximum operating current (mA)	95
Maximum standby current (mA)	30

Maximum Ratings

Exceeding maximum ratings may impair the useful life of the device. These user guidelines are not tested.

Storage temperature -65 °C to +150 °C

Ambient temperature with power applied -55 °C to +125 °C

Supply voltage to ground potential (Pin 24 to Pin 12) -0.5 V to +7.0 V

DC voltage applied to outputs in High Z state^[1] -0.5 V to $V_{CC} + 0.5$ V

DC input voltage^[1] -0.5 V to $V_{CC} + 0.5$ V

Output current into outputs (LOW) 20 mA

Static discharge voltage > 2001 V (per MIL-STD-883, Method 3015)

Latch up current > 200 mA

Operating Range

Range	Ambient Temperature	V_{CC}
Commercial	0 °C to +70 °C	5 V $\pm$ 10%

Electrical Characteristics

Over the Operating Range

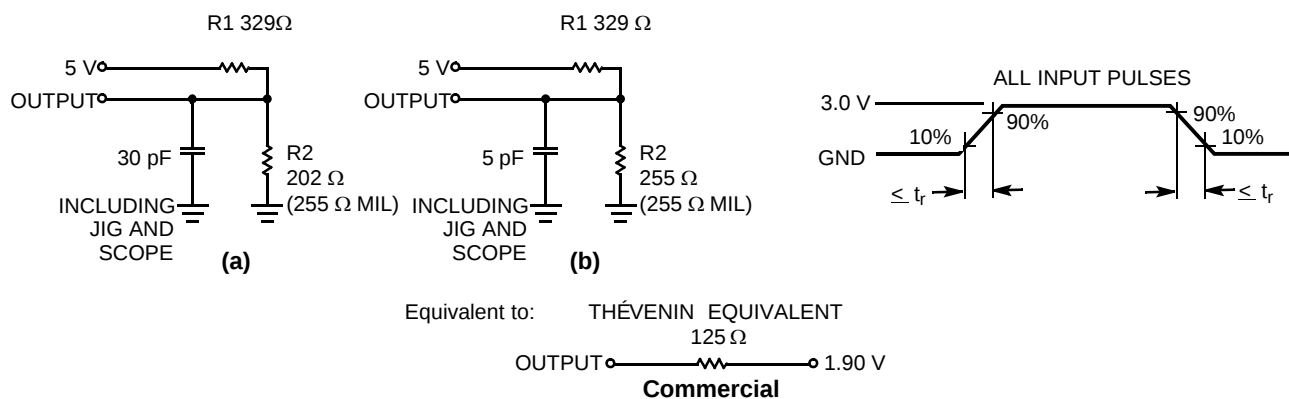
Parameter	Description	Test Conditions	-25		Unit
			Min	Max	
V_{OH}	Output HIGH voltage	$V_{CC} = \text{Min}$, $I_{OH} = -4.0$ mA	2.4	—	V
V_{OL}	Output LOW voltage	$V_{CC} = \text{Min}$, $I_{OL} = 12.0$ mA	—	0.4	V
V_{IH}	Input HIGH voltage		2.2	$V_{CC} + 0.3$ V	V
V_{IL}	Input LOW voltage ^[1]		-0.5	0.8	V
I_{IX}	Input load current	$GND \leq V_I \leq V_{CC}$	-5	+5	μ A
I_{OZ}	Output leakage current	$GND \leq V_O \leq V_{CC}$, Output Disabled	-5	+5	μ A
I_{OS}	Output short circuit current ^[2]	$V_{CC} = \text{Max}$, $V_{OUT} = GND$	—	-300	mA
I_{CC}	V_{CC} operating supply current	$V_{CC} = \text{Max}$, $I_{OUT} = 0$ mA, $f = f_{MAX} = 1/t_{RC}$	—	95	mA
I_{SB1}	Automatic $\overline{CE}$ power-down current—TTL inputs ^[3]	Max V_{CC} , $\overline{CE} \geq V_{IH}$, $V_{IN} \geq V_{IH}$ or $V_{IN} \leq V_{IL}$, $f = f_{MAX}$	—	30	mA
I_{SB2}	Automatic $\overline{CE}$ power-down current—CMOS inputs ^[3]	Max V_{CC} , $\overline{CE} \geq V_{CC} - 0.3$ V, $V_{IN} \geq V_{CC} - 0.3$ V or $V_{IN} < 0.3$ V	—	15	mA

Capacitance^[4]

Parameter	Description	Test Conditions	Max	Unit
C_{IN}	Input capacitance	$T_A = 25$ °C, $f = 1$ MHz, $V_{CC} = 5.0$ V	8	pF
C_{OUT}	Output capacitance		10	pF

Notes

- $V_{(min.)} = -2.0$ V for pulse durations of less than 20 ns.
- Not more than one output should be shorted at one time. Duration of the short circuit should not exceed 30 seconds.
- A pull-up resistor to V_{CC} on the $\overline{CE}$ input is required to keep the device deselected during V_{CC} power-up, otherwise I_{SB} will exceed values given.
- Tested initially and after any design or process changes that may affect these parameters.

Figure 2. AC Test Loads and Waveforms^[5]


Switching Characteristics

Over the Operating Range^[6]

Parameter	Description	-25		Unit
		Min	Max	
READ CYCLE				
t _{RC}	Read cycle time	25	–	ns
t _{AA}	Address to data valid	–	25	ns
t _{OHA}	Output hold from address change	3	–	ns
t _{ACE}	$\overline{CE}$ LOW to data valid	–	25	ns
t _{LZCE}	$\overline{CE}$ LOW to low Z ^[7]	3	–	ns
t _{HZCE}	$\overline{CE}$ HIGH to high Z ^[7, 8]	0	11	ns
t _{PU}	$\overline{CE}$ LOW to power-up	0	–	ns
t _{PD}	$\overline{CE}$ HIGH to power-down	–	20	ns
WRITE CYCLE ^[9]				
t _{WC}	Write cycle time	25	–	ns
t _{SCE}	$\overline{CE}$ LOW to write end	20	–	ns
t _{AW}	Address setup to write end	20	–	ns
t _{HA}	Address hold from write end	0	–	ns
t _{SA}	Address setup to write start	0	–	ns
t _{PWE}	$\overline{WE}$ pulse width	20	–	ns
t _{SD}	Data setup to write end	15	–	ns
t _{HD}	Data hold from write end	0	–	ns
t _{LZWE}	$\overline{WE}$ HIGH to low Z ^[7]	3	–	ns
t _{HZWE}	$\overline{WE}$ LOW to high Z ^[7, 8]	0	11	ns

Notes

- $t_r = \leq 5$ ns for the -25 and slower speeds.
- Test conditions assume signal transition time of 5 ns or less for -25 and slower speeds, timing reference levels of 1.5 V, input pulse levels of 0 to 3.0 V, and output loading of the specified I_{OL}/I_{OH} and 30-pF load capacitance.
- At any given temperature and voltage condition, t_{HZCE} is less than t_{LZCE} and t_{HZWE} is less than t_{LZWE} for any given device.
- t_{HZCE} and t_{HZWE} are specified with $C_L = 5$ pF as in part (b) in AC Test Loads and Waveforms. Transition is measured ± 500 mV from steady-state voltage.
- The internal write time of the memory is defined by the overlap of $\overline{CE}$ LOW and $\overline{WE}$ LOW. Both signals must be LOW to initiate a write and either signal can terminate a write by going HIGH. The data input set-up and hold timing should be referenced to the rising edge of the signal that terminates the write.

Switching Waveforms

Figure 3. Read Cycle No. 1^[10, 11]

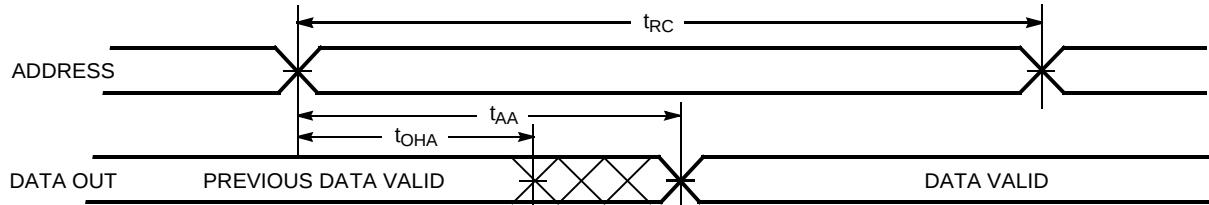


Figure 4. Read Cycle No. 2^[10]

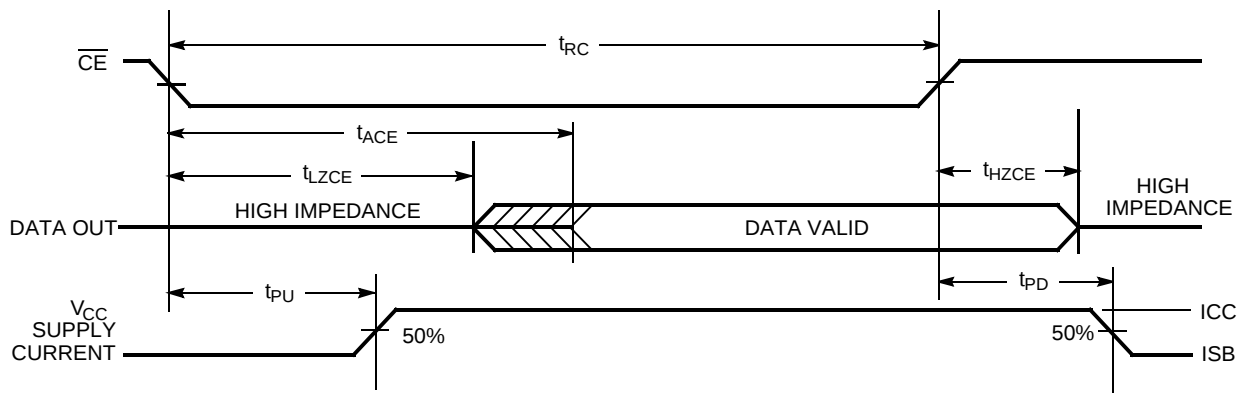
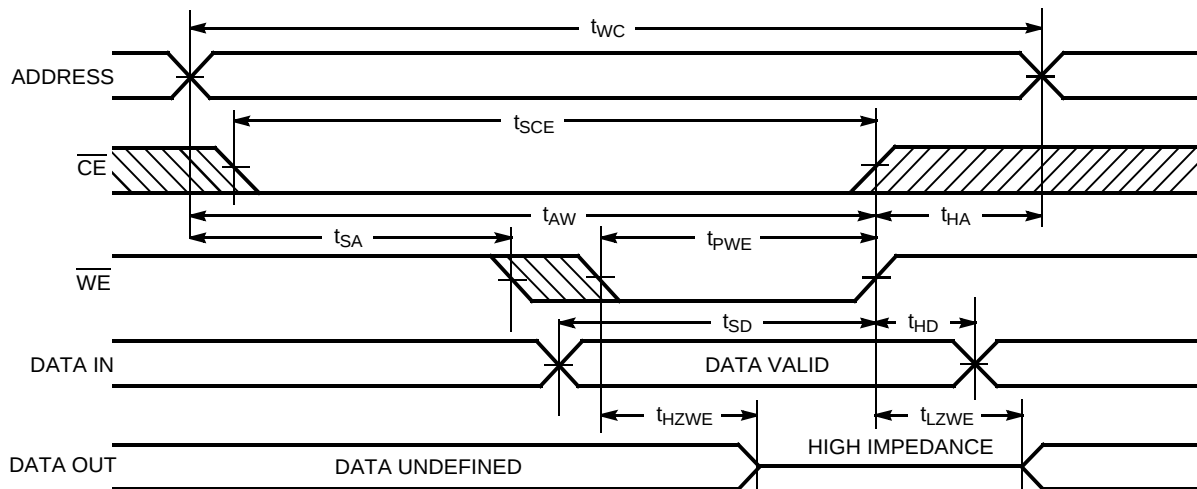


Figure 5. Write Cycle No. 1 (WE Controlled)^[12]



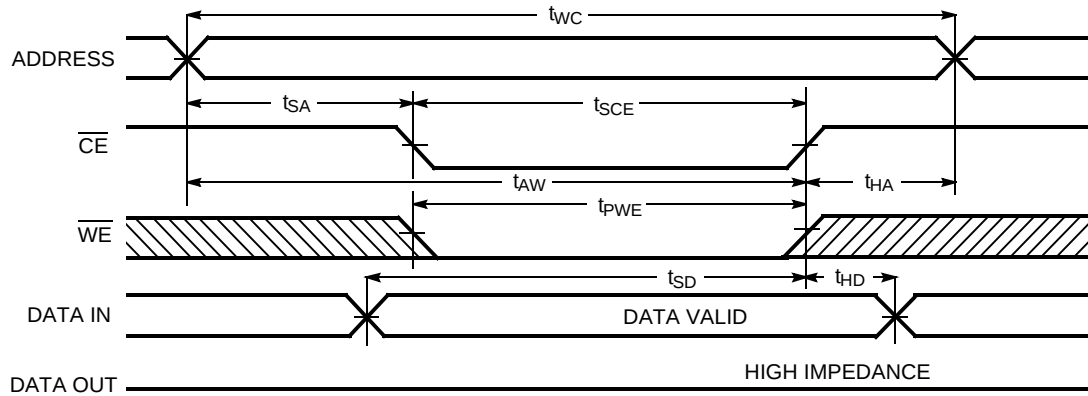
C197-8

Notes

10. WE is HIGH for read cycle.
11. Device is continuously selected, $\overline{CE} = V_{IL}$.
12. If CE goes HIGH simultaneously with WE HIGH, the output remains in a high-impedance state.

Switching Waveforms (continued)

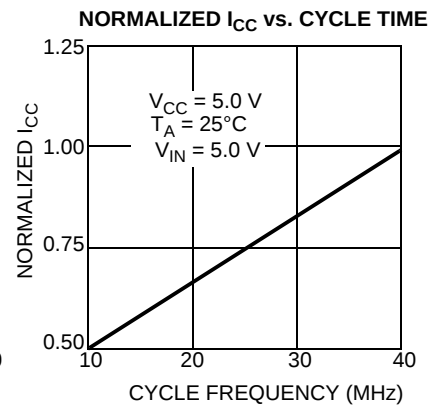
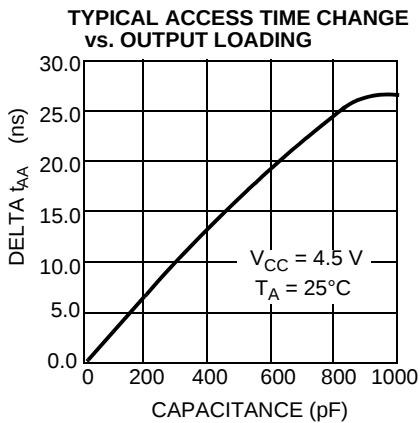
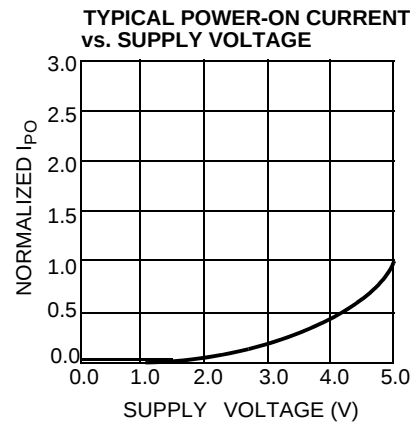
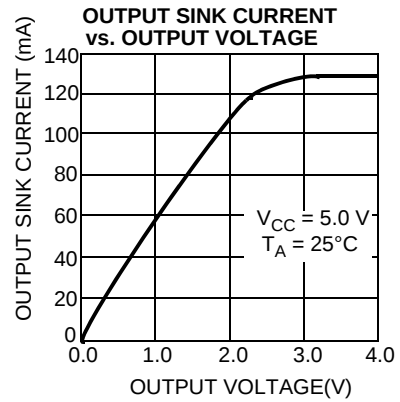
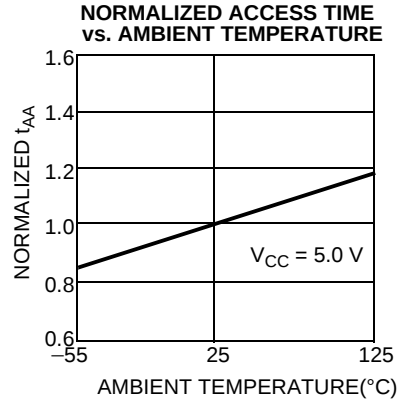
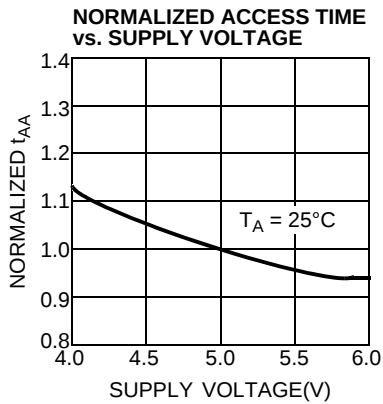
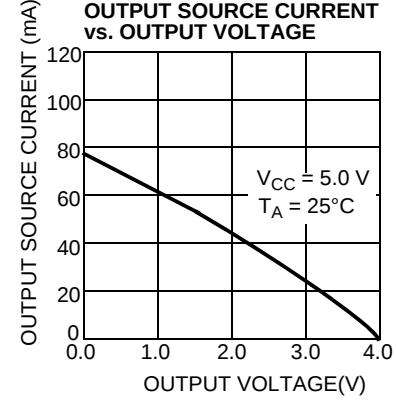
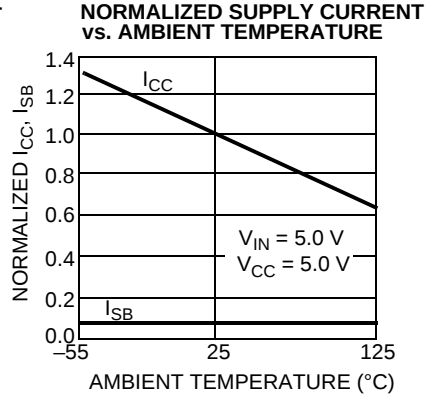
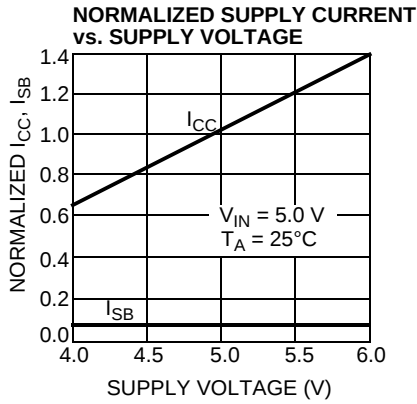
Figure 6. Write Cycle No. 2 ($\overline{\text{CE}}$ Controlled)^[13, 14]



Notes

13. The internal write time of the memory is defined by the overlap of $\overline{\text{CE}}$ LOW and $\overline{\text{WE}}$ LOW. Both signals must be LOW to initiate a write and either signal can terminate a write by going HIGH. The data input set-up and hold timing should be referenced to the rising edge of the signal that terminates the write.
14. If $\overline{\text{CE}}$ goes HIGH simultaneously with $\overline{\text{WE}}$ HIGH, the output remains in a high-impedance state.

Typical DC and AC Characteristics



CY7C197N Truth Table

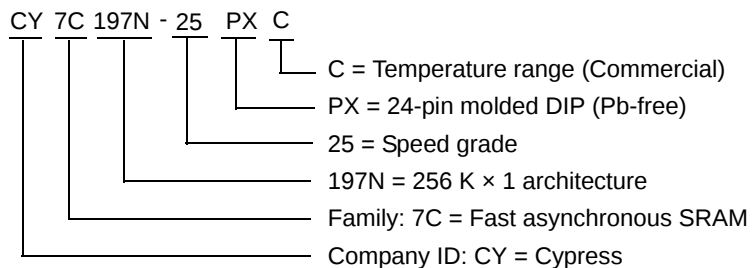
$\overline{\text{CE}}$	$\overline{\text{WE}}$	Input/Output	Mode
H	X	High Z	Deselect/Power-Down
L	H	Data Out	Read
L	L	Data In	Write

Ordering Information

Speed (ns)	Ordering Code	Package Diagram	Package Type	Operating Range
25	CY7C197N-25PXC	51-85013	24-pin (300-Mil) Molded DIP (Pb-free)	Commercial

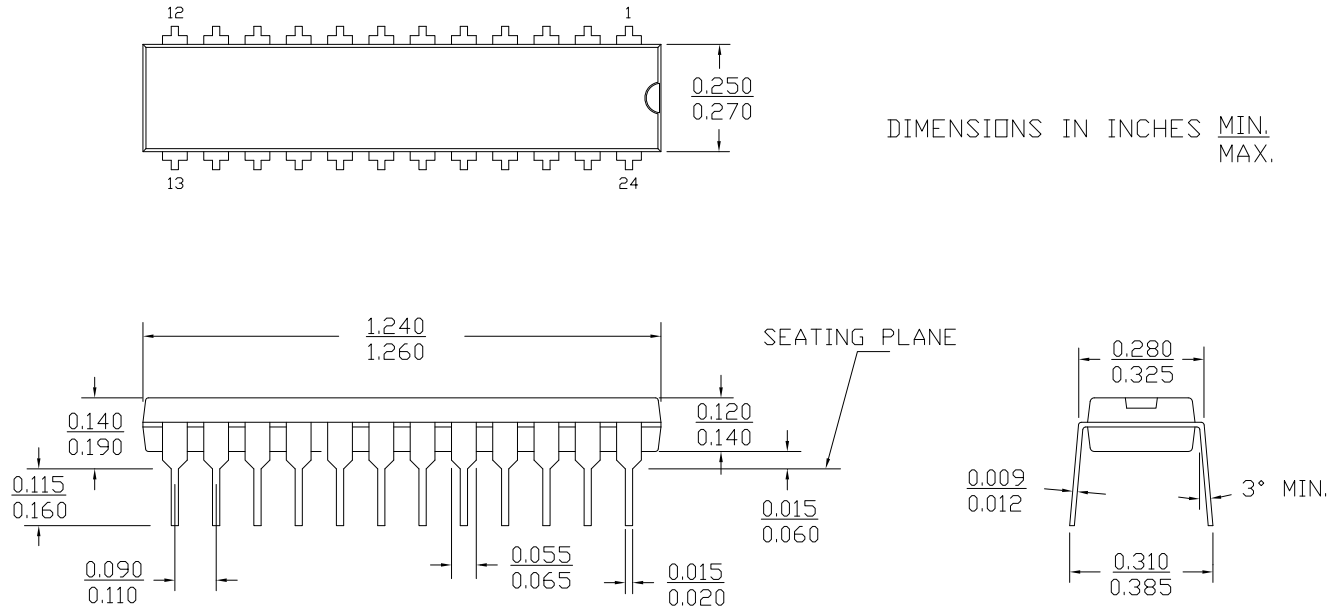
Contact your local sales representative regarding availability of these parts.

Ordering Code Definitions



Package Diagram

Figure 7. 24-pin (300-Mil) PDIP (51-85013)



51-85013 *C

Acronyms

Acronym	Description
CE	chip enable
CMOS	complementary metal oxide semiconductor
DIP	dual inline package
I/O	input/output
PDIP	plastic dual inline package
SRAM	static random access memory
TTL	transistor-transistor logic
WE	write enable

Document Conventions

Units of Measure

Symbol	Unit of Measure
%	percent
°C	degree Celsius
mA	milliamperes
MHz	megahertz
mV	millivolts
mW	milliwatts
ns	nanoseconds
pF	picofarads
V	volts
Ω	ohms
W	watts
μA	microamperes

Document History Page

Document Title: CY7C197N, 256 K × 1 Static RAM Document Number: 001-06495				
REV.	ECN NO.	Submission Date	Orig. of Change	Description of Change
**	424111	See ECN	NXR	New Data Sheet
*A	2958594	06/22/10	AJU	The EOL Prune part number CY7C197N-45PXC removed & Updated package diagram.
*B	3095450	11/25/2010	AJU	Updated template. Added Acronyms , Document Conventions , and Ordering Code Definitions Removed –45 information. Changed posting to external web.
*C	3246053	05/02/2011	PRAS	Updated in new template.
*D	3270287	07/01/2011	AJU	Fixed units in Electrical Characteristics table.

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